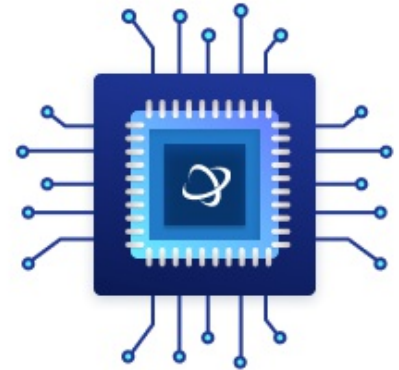


BROADBAND RF POWER LDMOS TRANSISTOR, 960-1215 MHz, 1000 W PEAK, 50 V



Images are for reference only

Manufacturers	NXP Semiconductor
Package/Case	NI-1230
Product Type	Transistors
RoHS	
Lifecycle	

Please submit RFQ for AFV121KHR5 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

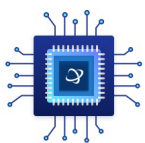


General Description

Features

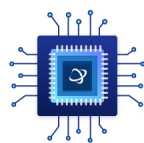
Airfast RF Power LDMOS Transistor, 1000 W Peak, 960-1215 MHz, 50 V

Related Products



[AFT20P060-4NR3](#)

NXP Semiconductor
OM-780-4



[AFT26HW050SR3](#)

NXP Semiconductor
NI-780-4S4



[2N7002PS](#)

NXP Semiconductor
SOT-363



[PSMN1R0-30YLD](#)

NXP Semiconductor
LFPK56



[PBSS4350Z](#)

NXP Semiconductor
SOT-223



[PBSS5350Z](#)

NXP Semiconductor
SOT223



[74LVC1G18GW](#)

NXP Semiconductor

SOT363



[PSMN1R0-40YLD](#)

NXP Semiconductor

N-channel